

# PTRA082808NF

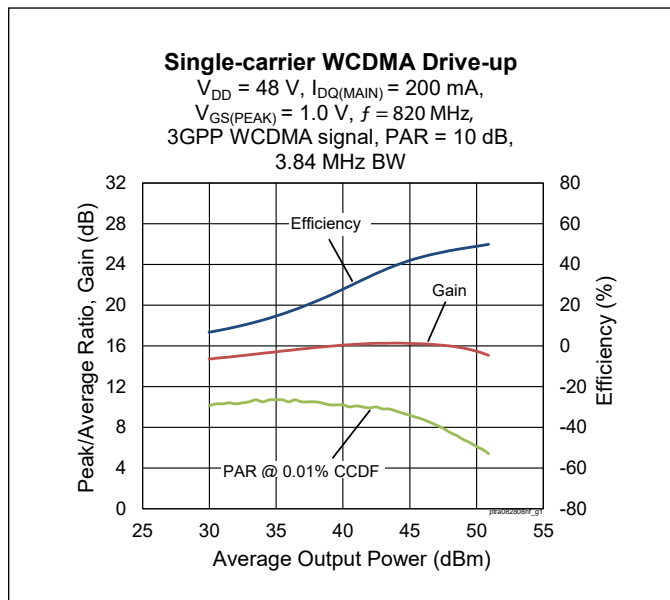
Thermally-Enhanced High Power RF LDMOS FET  
280 W, 48 V, 790 – 820 MHz



## Description

The PTRA082808NF is a 280-watt LDMOS FET intended for use in multi-standard cellular power amplifier applications in the 790 to 820 MHz frequency band. Features include input and output matching, high gain and thermally-enhanced package with earless flanges. Manufactured with an advanced LDMOS process, this device provides excellent thermal performance and superior reliability.

Package Types: PG-HBSOF-6-2



## Features

- Broadband internal input and output matching
- Asymmetrical design
  - Main:  $P_{1dB} = 115\text{ W Typ}$
  - Peak:  $P_{1dB} = 165\text{ W Typ}$
- Typical Pulsed CW performance, 820 MHz, 48 V, Doherty configuration
  - Output power at  $P_{3dB} = 250\text{ W}$
  - Efficiency = 55.6 %
  - Gain = 16.2 dB
- Capable of handling 10:1 VSWR @ 48 V, 56.2 W (CW) output power
- Human Body Model Class 1C (per ANSI/ESDA/JEDEC JS-001)
- Integrated ESD protection
- Low thermal resistance
- Pb-free and RoHS compliant

## RF Characteristics

### Single-carrier WCDMA Specifications (tested in the Doherty test fixture)

$V_{DD} = 48\text{ V}$ ,  $I_{DQ} = 200\text{ mA}$ ,  $V_{GS(PEAK)} = 1.0\text{ V}$ ,  $P_{OUT} = 56.2\text{ W avg}$ ,  $f = 820\text{ MHz}$ , 3GPP, channel bandwidth = 3.84 MHz, peak/average = 10 dB @ 0.01% CCDF

| Characteristic               | Symbol   | Min. | Typ.  | Max.  | Unit |
|------------------------------|----------|------|-------|-------|------|
| Gain                         | $G_{ps}$ | 15.2 | 15.5  | —     | dB   |
| Drain Efficiency             | $\eta_D$ | 42.7 | 44.5  | —     | %    |
| Adjacent Channel Power Ratio | ACPR     | —    | -36.4 | -33.5 | dBc  |
| Output PAR @ 0.01% CCDF      | OPAR     | 6.6  | 7.3   | —     | dB   |

Note:

All published data at  $T_{CASE} = 25^\circ\text{C}$  unless otherwise indicated

ESD: Electrostatic discharge sensitive device—observe handling precautions!



## DC Characteristics (each side)

| Characteristic                 | Symbol        | Min. | Typ. | Max.  | Unit          | Conditions                                        |
|--------------------------------|---------------|------|------|-------|---------------|---------------------------------------------------|
| Drain-Source Breakdown Voltage | $V_{BR(DSS)}$ | 105  | —    | —     | V             | $V_{GS} = 0\text{ V}$ , $I_{DS} = 10\text{ mA}$   |
| Drain Leakage Current          | $I_{DSS}$     | —    | —    | 1     | $\mu\text{A}$ | $V_{DS} = 50\text{ V}$ , $V_{GS} = 0\text{ V}$    |
|                                |               | —    | —    | 10    |               | $V_{DS} = 105\text{ V}$ , $V_{GS} = 0\text{ V}$   |
| Gate Leakage Current           | $I_{GSS}$     | —    | —    | 1     |               | $V_{GS} = 10\text{ V}$ , $V_{DS} = 0\text{ V}$    |
| On-State Resistance (main)     | $R_{DS(on)}$  | 0.07 | 0.3  | 0.66  | $\Omega$      | $V_{GS} = 10\text{ V}$ , $V_{DS} = 0.1\text{ V}$  |
| On-State Resistance (peak)     |               | 0.01 | 0.12 | 0.325 |               |                                                   |
| Operating Gate Voltage (main)  | $V_{GS}$      | 3.0  | 3.6  | 4.1   | V             | $V_{DS} = 3.6\text{ V}$ , $I_{DQ} = 0.2\text{ A}$ |
| Operating Gate Voltage (peak)  |               | —    | 1    | —     |               | $V_{DS} = 1.0\text{ V}$ , $I_{DQ} = 0\text{ A}$   |

## Maximum Ratings

| Parameter                 | Symbol    | Value       | Unit               |
|---------------------------|-----------|-------------|--------------------|
| Drain-source Voltage      | $V_{DSS}$ | 105         | V                  |
| Gate-source Voltage       | $V_{GS}$  | −6 to +12   |                    |
| Operating Voltage         | $V_{DD}$  | 0 to +55    |                    |
| Junction Temperature      | $T_J$     | 225         | $^{\circ}\text{C}$ |
| Storage Temperature Range | $T_{STG}$ | −65 to +150 |                    |

1. Operation above the maximum values listed here may cause permanent damage. Maximum ratings are absolute ratings; exceeding only one of these values may cause irreversible damage to the component. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. For reliable continuous operation, the device should be operated within the operating voltage range ( $V_{DD}$ ) specified above.

2. Parameters values can be affected by end application and product usage. Values may change over time.

## Thermal Characteristics

| Characteristics           | Symbol          | Value | Unit                 | Conditions                                  |
|---------------------------|-----------------|-------|----------------------|---------------------------------------------|
| Thermal Resistance (main) | $R_{\theta JC}$ | 0.766 | $^{\circ}\text{C/W}$ | $T_{CASE} = 70^{\circ}\text{C}$ , 56.2 W CW |
| Thermal Resistance (peak) |                 | 0.208 |                      | $T_{CASE} = 70^{\circ}\text{C}$ , 200 W CW  |

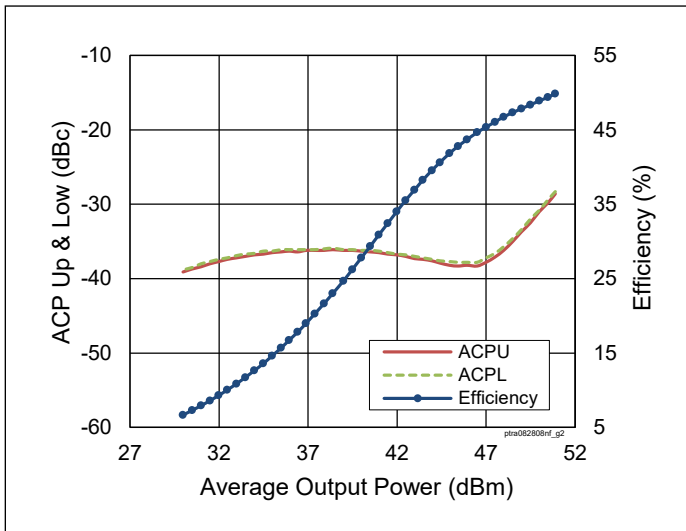
## Moisture Sensitivity Level

| Level | Test Signal         | Package Temperature | Unit               |
|-------|---------------------|---------------------|--------------------|
| 3     | IPC/JEDEC J-STD-020 | 260                 | $^{\circ}\text{C}$ |

## Ordering Information

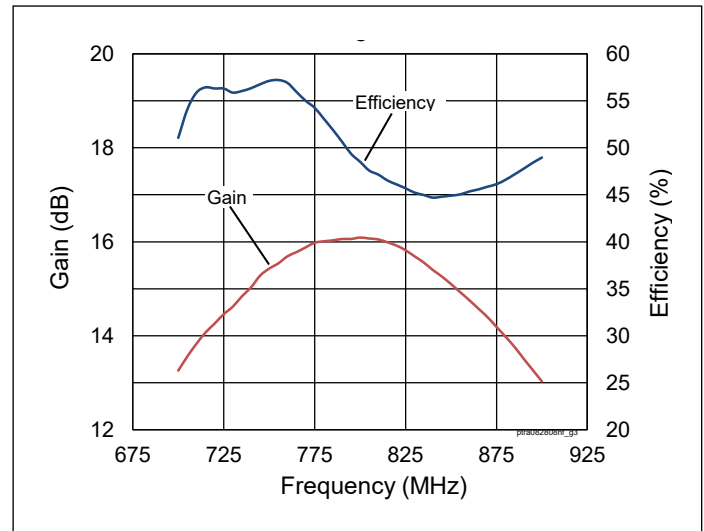
| Type and Version   | Order Code         | Package Description | Shipping             |
|--------------------|--------------------|---------------------|----------------------|
| PTRA082808NF V1 R5 | PTRA082808NF-V1-R5 | PG-HBSOF-6-2        | Tape & Reel, 500 pcs |

### Typical Performance (data taken in a production test fixture)



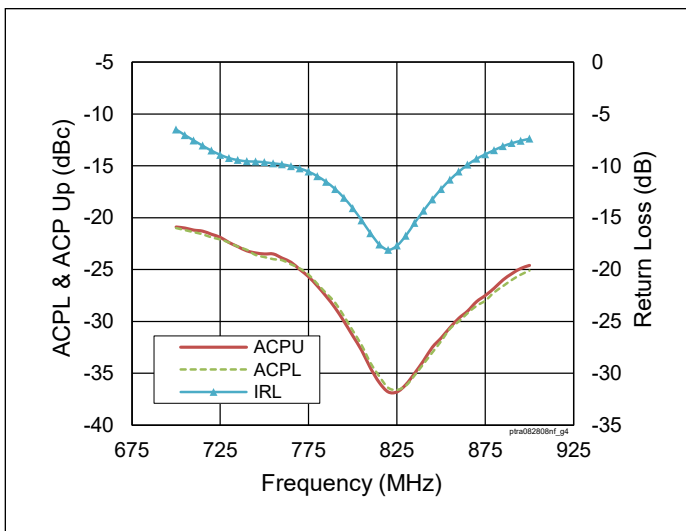
**Figure 1.** Single-carrier WCDMA Drive-up

$V_{DD} = 48\text{ V}$ ,  $I_{DQ(MAIN)} = 200\text{ mA}$ ,  
 $V_{GS(PEAK)} = 1.0\text{ V}$ ,  $f = 820\text{ MHz}$ ,  
 3GPP WCDMA signal, PAR = 10 dB,  
 BW = 3.84 MHz



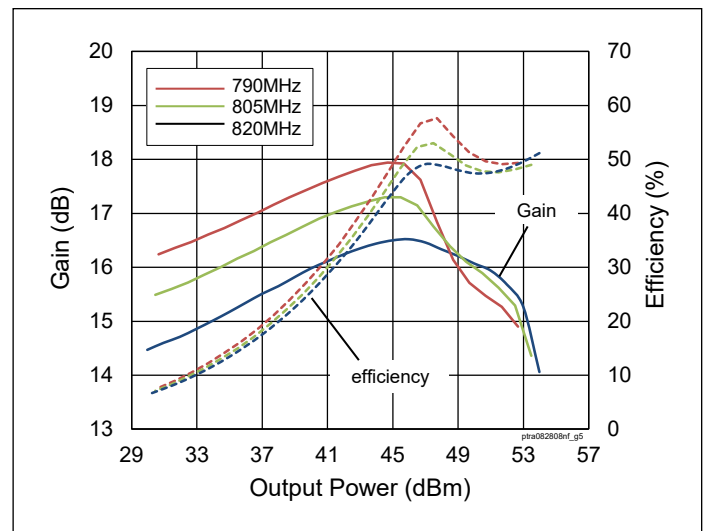
**Figure 2.** Single-carrier WCDMA Broadband Performance

$V_{DD} = 48\text{ V}$ ,  $I_{DQ(MAIN)} = 200\text{ mA}$ ,  
 $V_{GS(PEAK)} = 1.0\text{ V}$ ,  $P_{OUT} = 47.5\text{ dBm}$ ,  
 3GPP WCDMA signal, PAR = 10 dB



**Figure 3.** Single-carrier WCDMA Broadband Performance

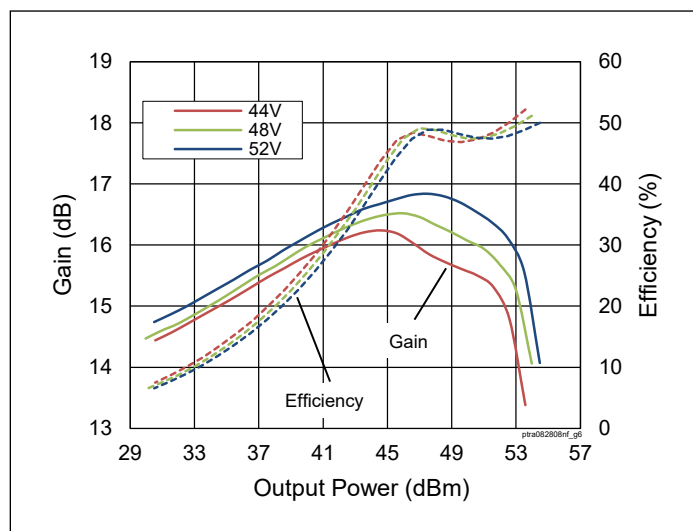
$V_{DD} = 48\text{ V}$ ,  $I_{DQ(MAIN)} = 200\text{ mA}$ ,  
 $V_{GS(PEAK)} = 1.0\text{ V}$ ,  $P_{OUT} = 47.5\text{ dBm}$ ,  
 3GPP WCDMA signal, PAR = 10 dB



**Figure 4.** CW Performance

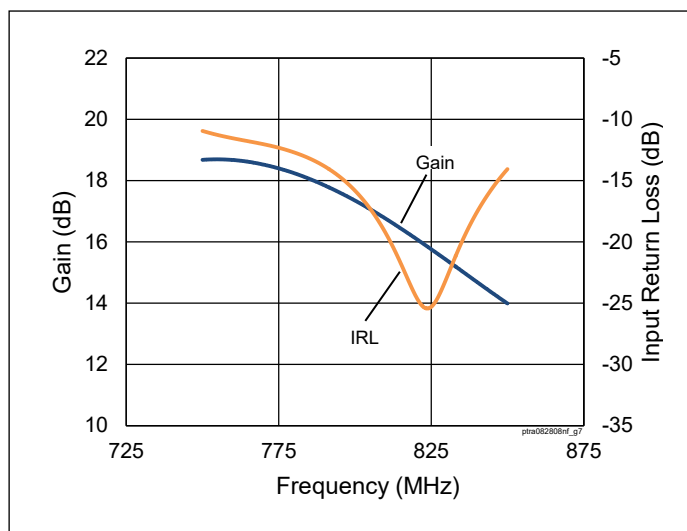
$V_{DD} = 48\text{ V}$ ,  $I_{DQ(MAIN)} = 200\text{ mA}$ ,  
 $V_{GS(PEAK)} = 1.0\text{ V}$

## Typical Performance (cont.)



**Figure 5.** CW Performance at various  $V_{DD}$

$I_{DQ(MAIN)} = 200 \text{ mA}$ ,  $V_{GS(PEAK)} = 1.0 \text{ V}$ ,  
 $f = 820 \text{ MHz}$



**Figure 6.** CW Performance Small Signal Gain & Input Return Loss

$V_{DD} = 48 \text{ V}$ ,  $I_{DQ(MAIN)} = 200 \text{ mA}$ ,  
 $V_{GS(PEAK)} = 1.0 \text{ V}$

## Load Pull Performance

**Main Side Load Pull Performance** – Pulsed CW signal: 10  $\mu$ s, 10% duty cycle, 48 V,  $I_{DQ} = 250$  mA

| $P_{1dB}$        |                 |                 |           |                        |                      |              |                      |           |                        |                      |              |
|------------------|-----------------|-----------------|-----------|------------------------|----------------------|--------------|----------------------|-----------|------------------------|----------------------|--------------|
| Max Output Power |                 |                 |           |                        |                      |              | Max Drain Efficiency |           |                        |                      |              |
| Freq [MHz]       | Zs [ $\Omega$ ] | Zl [ $\Omega$ ] | Gain [dB] | P <sub>1dB</sub> [dBm] | P <sub>1dB</sub> [W] | $\eta_D$ [%] | Zl [ $\Omega$ ]      | Gain [dB] | P <sub>1dB</sub> [dBm] | P <sub>1dB</sub> [W] | $\eta_D$ [%] |
| 790              | 1.8 – j4.4      | 2.4 – j1.6      | 20.24     | 51.73                  | 149                  | 58.9         | 5.4 + j2.6           | 22.49     | 48.72                  | 74                   | 69.8         |
| 805              | 1.8 – j5.2      | 2.6 – j1.8      | 20.28     | 51.47                  | 140                  | 58.6         | 5.4 + j2.5           | 22.41     | 48.74                  | 75                   | 70.2         |
| 820              | 1.8 – j5.2      | 2.9 – j1.8      | 20.65     | 51.41                  | 138                  | 60.9         | 5.3 + j1.9           | 22.51     | 48.97                  | 79                   | 70.4         |

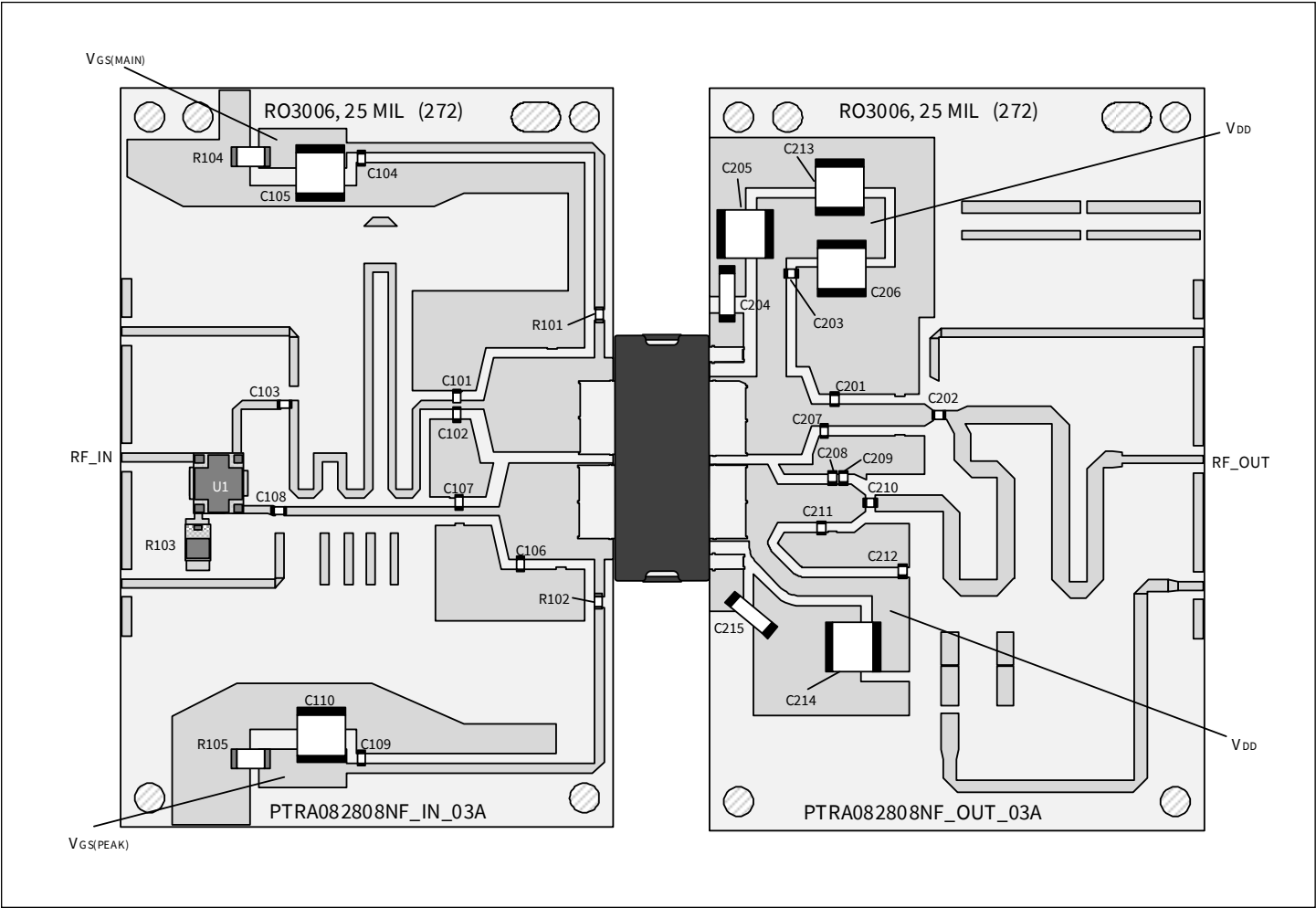
| $P_{3dB}$        |                 |                 |           |                        |                      |              |                      |           |                        |                      |              |
|------------------|-----------------|-----------------|-----------|------------------------|----------------------|--------------|----------------------|-----------|------------------------|----------------------|--------------|
| Max Output Power |                 |                 |           |                        |                      |              | Max Drain Efficiency |           |                        |                      |              |
| Freq [MHz]       | Zs [ $\Omega$ ] | Zl [ $\Omega$ ] | Gain [dB] | P <sub>3dB</sub> [dBm] | P <sub>3dB</sub> [W] | $\eta_D$ [%] | Zl [ $\Omega$ ]      | Gain [dB] | P <sub>3dB</sub> [dBm] | P <sub>3dB</sub> [W] | $\eta_D$ [%] |
| 790              | 1.8 – j4.4      | 2.6 – j1.9      | 18.3      | 52.53                  | 179                  | 62.7         | 5.5 + j0.2           | 20.27     | 50.63                  | 116                  | 71.2         |
| 805              | 1.8 – j5.2      | 2.8 – j2.6      | 18.3      | 52.29                  | 169                  | 60.2         | 5.6 + j0.0           | 20.18     | 50.61                  | 115                  | 71.2         |
| 820              | 1.8 – j5.2      | 2.9 – j3.1      | 18.4      | 52.24                  | 168                  | 60.0         | 5.6 + j1             | 20.45     | 50.13                  | 103                  | 71.3         |

**Peak Side Load Pull Performance** – Pulsed CW signal: 10  $\mu$ s, 10% duty cycle, 48 V,  $I_{DQ} = 350$  mA

| $P_{1dB}$        |                 |                 |           |                        |                      |              |                      |           |                        |                      |              |
|------------------|-----------------|-----------------|-----------|------------------------|----------------------|--------------|----------------------|-----------|------------------------|----------------------|--------------|
| Max Output Power |                 |                 |           |                        |                      |              | Max Drain Efficiency |           |                        |                      |              |
| Freq [MHz]       | Zs [ $\Omega$ ] | Zl [ $\Omega$ ] | Gain [dB] | P <sub>1dB</sub> [dBm] | P <sub>1dB</sub> [W] | $\eta_D$ [%] | Zl [ $\Omega$ ]      | Gain [dB] | P <sub>1dB</sub> [dBm] | P <sub>1dB</sub> [W] | $\eta_D$ [%] |
| 790              | 1.5 – j4.1      | 1.8 – j1.3      | 16.26     | 53.30                  | 214                  | 60.4         | 3.9 + j1.2           | 17.03     | 50.89                  | 123                  | 72.8         |
| 805              | 1.5 – j4.1      | 1.9 – j1.3      | 16.02     | 53.07                  | 203                  | 60.1         | 3.6 + j1.3           | 16.84     | 50.77                  | 119                  | 73.2         |
| 820              | 1.4 – j4.6      | 2.0 – j1.4      | 16.4      | 53.00                  | 200                  | 61.0         | 3.1 + j2.2           | 16.87     | 50.78                  | 120                  | 73.0         |

| $P_{3dB}$        |                 |                 |           |                        |                      |              |                      |           |                        |                      |              |
|------------------|-----------------|-----------------|-----------|------------------------|----------------------|--------------|----------------------|-----------|------------------------|----------------------|--------------|
| Max Output Power |                 |                 |           |                        |                      |              | Max Drain Efficiency |           |                        |                      |              |
| Freq [MHz]       | Zs [ $\Omega$ ] | Zl [ $\Omega$ ] | Gain [dB] | P <sub>3dB</sub> [dBm] | P <sub>3dB</sub> [W] | $\eta_D$ [%] | Zl [ $\Omega$ ]      | Gain [dB] | P <sub>3dB</sub> [dBm] | P <sub>3dB</sub> [W] | $\eta_D$ [%] |
| 790              | 1.5 – j4.1      | 2.0 – j1.4      | 14.37     | 54.07                  | 255                  | 65.3         | 3.6 – j0.1           | 15.05     | 52.54                  | 180                  | 73.9         |
| 805              | 1.5 – j4.1      | 2.0 – j2.3      | 14.84     | 53.86                  | 243                  | 60.5         | 3.7 + j1.2           | 14.84     | 51.42                  | 139                  | 73.8         |
| 820              | 1.4 – j4.6      | 2.1 – j1.5      | 14.43     | 53.77                  | 238                  | 64.0         | 3.6 + j0.7           | 15.13     | 51.83                  | 152                  | 73.6         |

Evaluation Board, 790 – 820 MHz



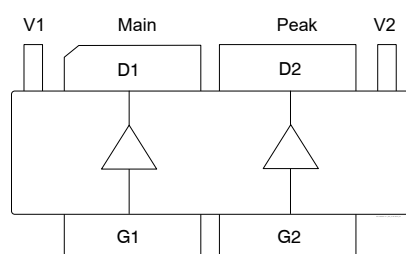
Reference circuit assembly diagram (not to scale)

|                              |                                                                                               |
|------------------------------|-----------------------------------------------------------------------------------------------|
| Evaluation Board Part Number | LTA/PTRA082808NF-V1                                                                           |
| PCB Information              | Rogers 3006, 0.635 mm [0.025"] thick, 2 oz. copper, $\epsilon_r = 3.66$ , $f = 790 - 820$ MHz |

## Components Information

| Component                          | Description                  | Manufacturer                    | P/N                 |
|------------------------------------|------------------------------|---------------------------------|---------------------|
| Input                              |                              |                                 |                     |
| C101, C102                         | Capacitor, 5.6 pF            | ATC                             | ATC800A5R6CT250T    |
| C103, C104, C108, C109             | Capacitor, 56 pF             | ATC                             | ATC800A560JT250T    |
| C105, C110                         | Capacitor, 10 $\mu$ F        | TDK Corporation                 | C5750X5R1H106K230KA |
| C106                               | Capacitor, 10 pF             | ATC                             | ATC800A100JT250T    |
| C107                               | Capacitor, 1.5 pF            | ATC                             | ATC800A1R5CT250T    |
| R101, R102                         | Resistor, 10 ohms            | Panasonic Electronic Components | ERJ-8GEYJ100V       |
| R103                               | Resistor, 50 ohms            | Anaren                          | C8A50Z4A            |
| R104, R105                         | Resistor, 1000 ohms          | Panasonic Electronic Components | ERJ-8GEYJ102V       |
| U1                                 | Hybrid Coupler               | Anaren                          | X3C07P1-05S         |
| Output                             |                              |                                 |                     |
| C201                               | Capacitor, 3.0 pF            | ATC                             | ATC800A3R0CT250T    |
| C202                               | Capacitor, 15 pF             | ATC                             | ATC800A150JT250T    |
| C203, C210, C212                   | Capacitor, 82 pF             | ATC                             | ATC800A820JT250T    |
| C204, C205, C206, C213, C214, C215 | Capacitor, 10 $\mu$ F , 100V | TDK Corporation                 | C5750X7S2A106M230KB |
| C207                               | Capacitor, 6.8 pF            | ATC                             | ATC800A6R8CT250T    |
| C208                               | Capacitor, 3.9 pF            | ATC                             | ATC800A3R9CT250T    |
| C209                               | Capacitor, 2.2 pF            | ATC                             | ATC800A2R2CT250T    |
| C211                               | Capacitor, 10 pF             | ATC                             | ATC800A100JT250T    |

## Pinout Diagram (top view)



| Pin    | Description                        |
|--------|------------------------------------|
| D1     | Drain Device 1 (Main)              |
| D2     | Drain Device 2 (Peak)              |
| G1     | Gate Device 1 (Main)               |
| G2     | Gate Device 2 (Peak)               |
| S      | Source (flange)                    |
| V1, V2 | Drain video decoupling, no DC bias |

# Package Outline Specifications – Package PG-HBSOF-6-2 (top view)

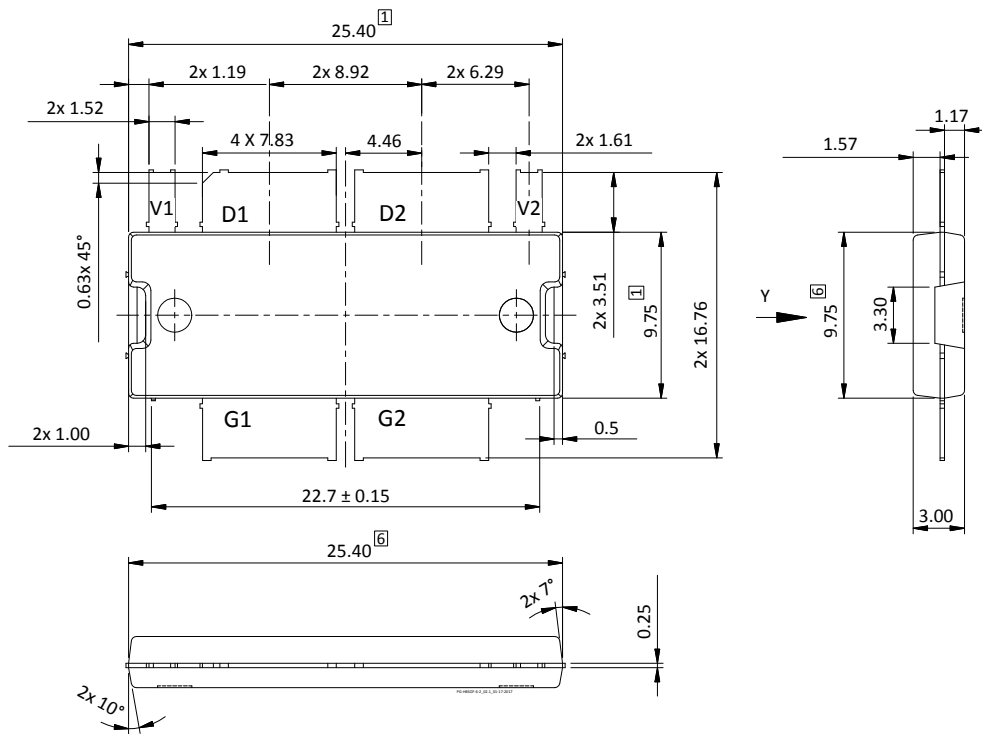


Diagram Notes—unless otherwise specified:

- [1] Mold/dam bar/metal protrusion of 0.30 mm max per side not included.
- [2] Metal protrusions are connected to source and shall not exceed 0.10 mm max.
3. Fillets and radii: all radii are 0.3 mm max.
4. Interpret dimensions and tolerances per ISO 8015.
5. Dimensions are mm.
- [6] Does not include mold/dam bar and metal protrusion.
- [7] Exposed metal surface is tin-plated, may not be covered by mold compound.
8. All tolerances  $\pm 0.1$  mm unless specified otherwise.
9. All metal surfaces are tin-plated, except area of cut.
10. Lead thickness: 0.25 mm.
11. Pins: D1, D2 = drain; G1, G2 = gate; V1, V2 = drain video decoupling, no DC bias

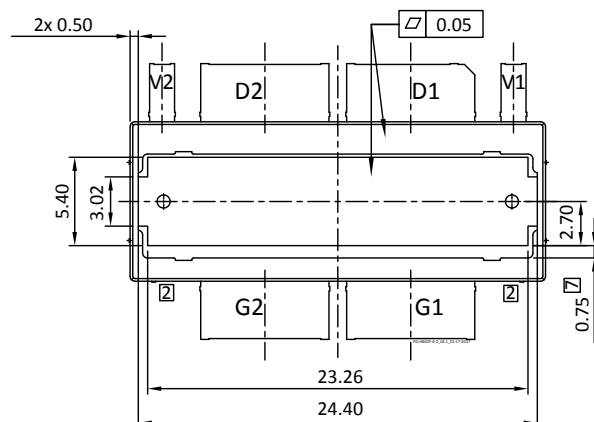
**Package Outline Specifications (cont.) – Package PG-HBSOF-6-2 (bottom view)**


Diagram Notes—unless otherwise specified:

1. Mold/dam bar/metal protrusion of 0.30 mm max per side not included.
2. Metal protrusions are connected to source and shall not exceed 0.10 mm max.
3. Fillets and radii: all radii are 0.3 mm max.
4. Interpret dimensions and tolerances per ISO 8015.
5. Dimensions are mm.
6. Does not include mold/dam bar and metal protrusion.
7. Exposed metal surface is tin-plated, may not be covered by mold compound.
8. All tolerances  $\pm 0.1$  mm unless specified otherwise.
9. All metal surfaces are tin-plated, except area of cut.
10. Lead thickness: 0.25 mm.
11. Pins: D1, D2 = drain; G1, G2 = gate; V1, V2 = drain video decoupling, no DC bias

## Notes & Disclaimer

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